WHAT IS CLAIMED IS:

- 1. A self-light-emitting device having an EL element, said EL element comprising:
- a TFT:
- a pixel electrode electrically connected to said TFT;
- an EL layer formed on said pixel electrode; and
- a cathode formed on said EL layer,

wherein a protective portion formed of an insulator is provided in an electrode hole.

- 2. A self-light-emitting device having an EL element, said EL element comprising:
- a TFT;
- a pixel electrode electrically connected to said TFT:
- an EL layer formed on said pixel electrode; and
- a cathode formed on said EL layer,

wherein a protective portion provided in an electrode hole is sandwiched between said pixel electrode and said EL layer.

- 3. A self-light-emitting device having an EL element, said EL element comprising:
- a TFT:
- a pixel electrode electrically connected to said TFT;
- an EL layer formed on said pixel electrode; and
- a cathode formed on said EL layer,
- wherein a protective portion provided in an electrode hole is formed of an insulator and said EL layer is formed on surfaces of said pixel electrode and said protective portion.

- 4. A self-light-emitting device having an EL element, said EL element comprising:
- a TFT;
- a pixel electrode electrically connected to said TFT;
- an EL layer formed on said pixel electrode; and
- a cathode formed on said EL layer,

wherein said EL layer and a protective portion are sandwiched between said pixel electrode and said cathode.

- 5. A self-light-emitting device having an EL element, said EL element comprising:
- a TFT;
- a pixel electrode electrically connected to said TFT;
- an EL layer formed on said pixel electrode; and
- a cathode formed on said EL layer,

wherein a plurality of said pixel electrodes are formed in a pixel portion and a protective portion is formed in a space between said pixel electrodes.

- 6. A self-light-emitting device according to any one of claims 1 to 5, wherein a surface of said pixel electrode and a surface of said protective portion are planarized to be flush with each other.
- 7. An electric equipment, which uses a self-light-emitting device according to any one of claims 1 to 5, as a display portion or a light source.

8. A method of manufacturing a self-light-emitting device comprising the steps of:

forming on a substrate a TFT and a pixel electrode electrically connected to said

TFT;

forming an insulating film on said pixel electrode; and forming a protective portion by selectively etching said insulating film.

9. A method of manufacturing a self-light-emitting device comprising the steps of: forming on a substrate a TFT and a pixel electrode electrically connected to said

TFT:

TFT;

forming an organic resin film on said pixel electrode; and forming a protective portion by selectively etching said organic resin film.

10. A method of manufacturing a self-light-emitting device comprising the steps of: forming on a substrate a TFT and a pixel electrode electrically connected to said

forming an organic resin film on said pixel electrode; and
forming a protective portion in an electrode hole and in a space between said pixel
electrodes by selectively etching said organic resin film.

11. A self-light emitting device comprising:

at least two first electrodes formed over a substrate with a gap between said first electrodes;

an insulating layer formed in the gap between said first electrodes; an EL layer formed on said first electrodes and said insulating layer; and a second electrode opposed to said at least two first electrodes with said EL layer interposed therebetween.

- 12. The self-light emitting device according to claim 11 wherein said first electrodes function as an anode while said second electrode functions as a cathode.
- 13. The self-light emitting device according to claim 11 wherein said self-light emitting device is a passive display device.
- 14. The self-light emitting device according to claim 11 wherein said EL layer comprises an organic electroluminescence material.
 - 15. A self-light emitting device comprising:
 - at least one switching element;
 - at least one interlayer insulating film formed over said switching element;
 - a contact hole opened in said switching element;
- a pixel electrode formed on said interlayer insulating film and electrically connected to said switching element through said contact hole;
 - an insulating layer formed on a portion of said pixel electrode in said contact hole;
 - an EL layer formed on said pixel electrode and said insulating layer; and
 - a second electrode formed on said EL layer.
- 16. The self-light emitting device according to claim 15 wherein said switching element comprises a thin film transistor.

- 17. The self-light emitting device according to claim 15 wherein said switching element comprises a transistor formed within a silicon substrate.
- 18. The self-light emitting device according to claim 15 wherein said pixel electrode is an anode while said second electrode is a cathode.
- 19. The self-light emitting device according to claim 15 wherein said pixel electrode is a cathode while said second electrode is an anode.
- 20. The self-light emitting device according to claim 15 wherein said EL layer comprises at least one organic EL layer.
- 21. The self-light emitting device according to claim 15 wherein said a surface of said insulating layer is substantially flush with a surface of said pixel electrode.
 - 22. A self-light emitting device comprising:
 - at least first and second switching elements;
 - at least one interlayer insulating film formed over said first and second switching elements;
 - at least first and second pixel electrodes formed over said interlayer insulating film wherein said first and second pixel electrodes are electrically connected to said first and second switching elements, respectively;

an insulating layer formed in a gap between said first and second pixel electrodes;

an EL layer formed on said first and second pixel electrodes and said insulating layer; and

a third electrode formed on said EL layer opposed to said first and second pixel electrodes.

- 23. The self-light emitting device according to claim 22 wherein said switching element comprises a thin film transistor.
- element comprises a transistor formed within a silicon substrate.

 25. The self-light emitting device according to claim 22 wherein ea and second pixel electrodes is an anode while said third electrode is a cathode. 24. The self-light emitting device according to claim 22 wherein said switching
 - 25. The self-light emitting device according to claim 22 wherein each of said first
 - 26. The self-light emitting device according to claim 22 wherein each of said first and second pixel electrodes is a cathode while said third electrode is an anode.
 - 27. The self-light emitting device according to claim 22 wherein said EL layer comprises at least one organic EL layer.
 - 28. The self-light emitting device according to claim 22 wherein a surface of said insulating layer is substantially flush with a surface of said first and second pixel electrodes.
 - 29. An electronic device having the self-light emitting device according to claim 11.

- 30. An electronic device having the self-light emitting device according to claim 15.
- 31. An electronic device having the self-light emitting device according to claim 22.
- 32. An electronic device according to claim 29 wherein said electronic device is selected from the group consisting of a video camera, a head mounted EL display, an image playback device, a portable computer, a personal computer, a cellular phone and an audio playback device.
- 33. An electronic device according to claim 30 wherein said electronic device is selected from the group consisting of a video camera, a head mounted EL display, an image playback device, a portable computer, a personal computer, a cellular phone and an audio playback device.
- 34. An electronic device according to claim 31 wherein said electronic device is selected from the group consisting of a video camera, a head mounted EL display, an image playback device, a portable computer, a personal computer, a cellular phone and an audio playback device.